



Surface Dielectric Characteristics of GFRP and PTFE in Cryogenic Environment under the Switching Impulse Superimposed on DC Voltage

Background

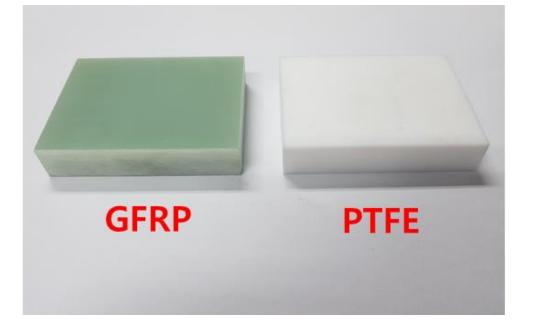
- Insulation of the DC circuit breaker combined with the superconductin superimposed due to the generation of a switching impulse waveform
- When voltage sources of different polarities are superimposed, the f are superimposed, it causes more serious stress in the system.
- Therefore, for the insulation design of the DC circuit breaker combine analyze the surface insulation characteristics according to the superi insulators.

Aim of work

- In order to obtain the surface insulation properties of the solid insu current-limiting module, GFRP and PTFE were selected as insulation ma
- For the insulation problem of DC circuit breaker combined with super-DC+SI superimposing surface dielectric breakdown experiment of GFR

Experiment Set-up

- In order to measure surface dielectric breakdown of DC and SI supe the specimens were made of 50x50x15 mm GFRP and PTFE as shown
- As shown in Fig. 2, a jig was manufactured so that the solid insulate electrode used in the experiment, the edge of the electrode was recorona phenomenon at the edge of the electrode, and the rod-shaped
- In order to check the surface insulation properties of GFRP and PTFE 15, 20 [mm].
- The surface breakdown was configured as shown in Fig. 3, and liquid be sufficiently submerged.
- In order to prevent the formation of bubbles in liquid nitrogen, the pressurizing with gaseous nitrogen.



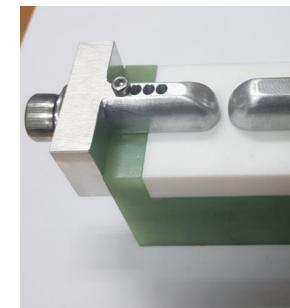


Fig. 1 Prepare two kind of specimens

Fig. 2 Configuration

Conclusion

- As a result of comparing the surface dielectric strength of GFRP and breakdown voltage decreases as the gap distance increases.
- The surface dielectric strength of GFRP and PTFE is the weakest when
- It will be helpful in estimating the separation distance of solid insulation using the experiment result of superimposed DC + SI surface dielectric breakdown according to the gap distance.

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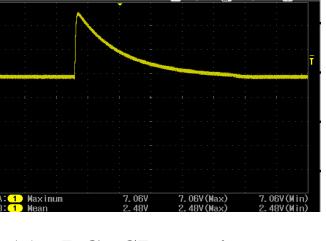
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ng current-limiting module may cause a big problem when DC and SI n.	Aa
ault voltage can be reduced, but when voltages of the same polarity	a tł
ed with the superconducting current-limiting module, it is essential to imposing switching impulse waveform during DC operation of solid	◆ D u a
ulator of the DC circuit breaker combined with the superconducting naterials.	
rconducting current-limiting module and compactness of the product, RP and PTFE was performed.	
erimposed voltages of solid insulators according to the gap distance, in the fig.1	
for could be placed in the jig and adhered to the electrode. For the ounded with R10 to prevent electric field concentration due to the delectrode was cut at 180 degrees to adhere to the specimen.	GFRP
according to the gap distance, the gap distance was selected as 5, 10,	
nitrogen was filled in the cryostat so that the experimental jig could	
experiment was conducted after maintaining a pressure of 3 bar by	
Image: Second	PTFE
GNZ Vacuum Pump Vacuum Pump	•
n of test jig Fig. 3 surface breakdown test set-up	
PTFE, GFRP is superior to PTFE, but the difference in surface dielectric	
voltages of the same polarity are superimposed.	

DC+SI superimposition system

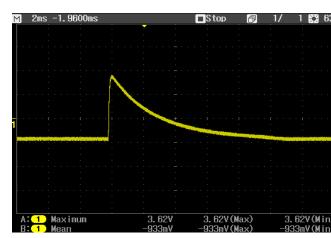
DC+SI superimposition system was constructed using a switching impulse generator, a DC generator, and a superposition facility, as shown in Fig. 4. The switching impulse generator and blocking capacitor were connected in series, and the DC generator was also connected in series with the protection resistor. The blocking capacitor and the protective resistor were connected in series to he superimposing equipment and the experiment was performed.

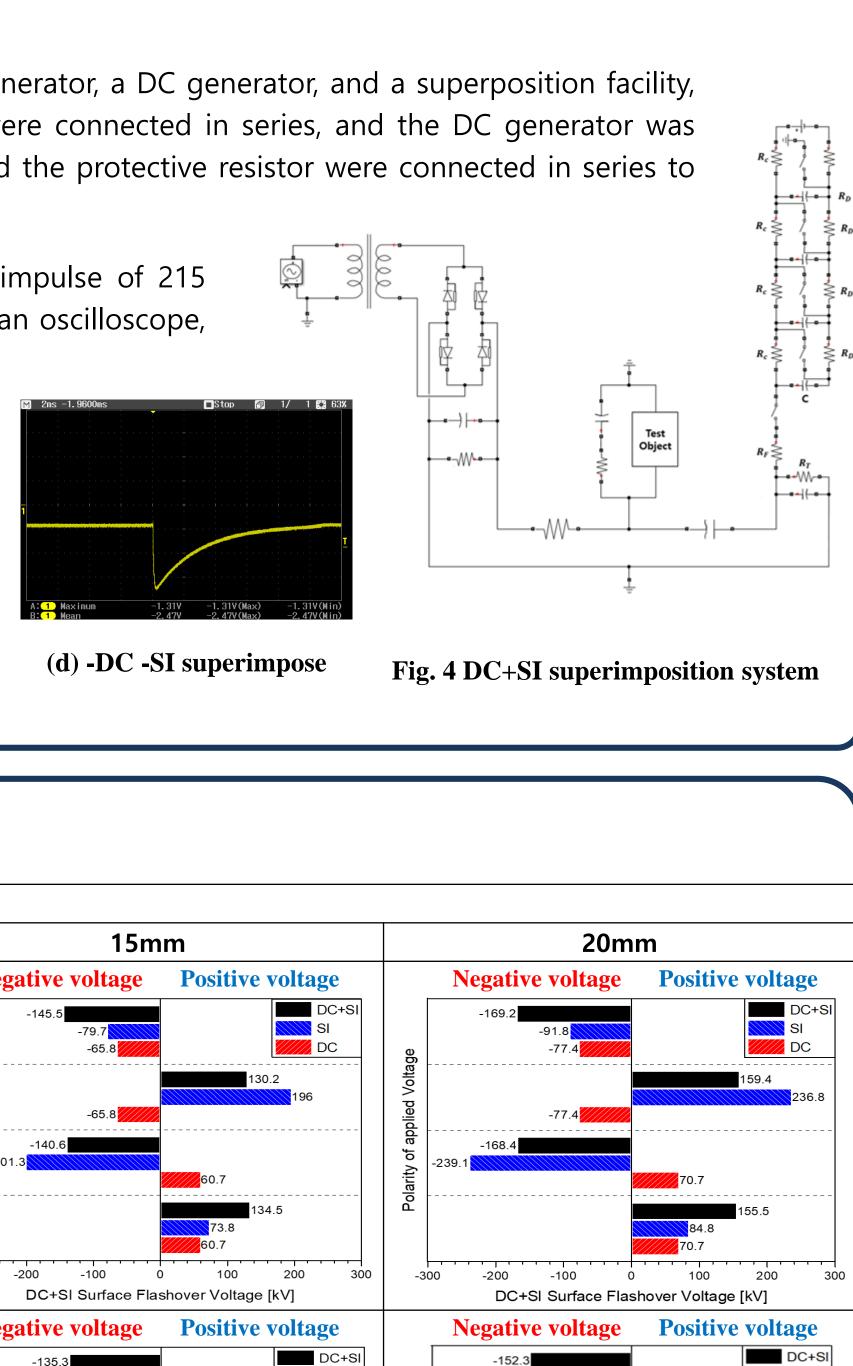
DC positive and DC negative voltages of less than 3% ripple and switching impulse of 215 us/2390 us were used. The superimposed DC+SI voltage was checked through an oscilloscope, as shown in Fig. 5.



(a) +DC +SI superimpose







(b) +DC -SI superimpose (c) -DC +SI superimpose

Fig. 5 Superimposed DC+SI voltage wave

Experiment result and discussion

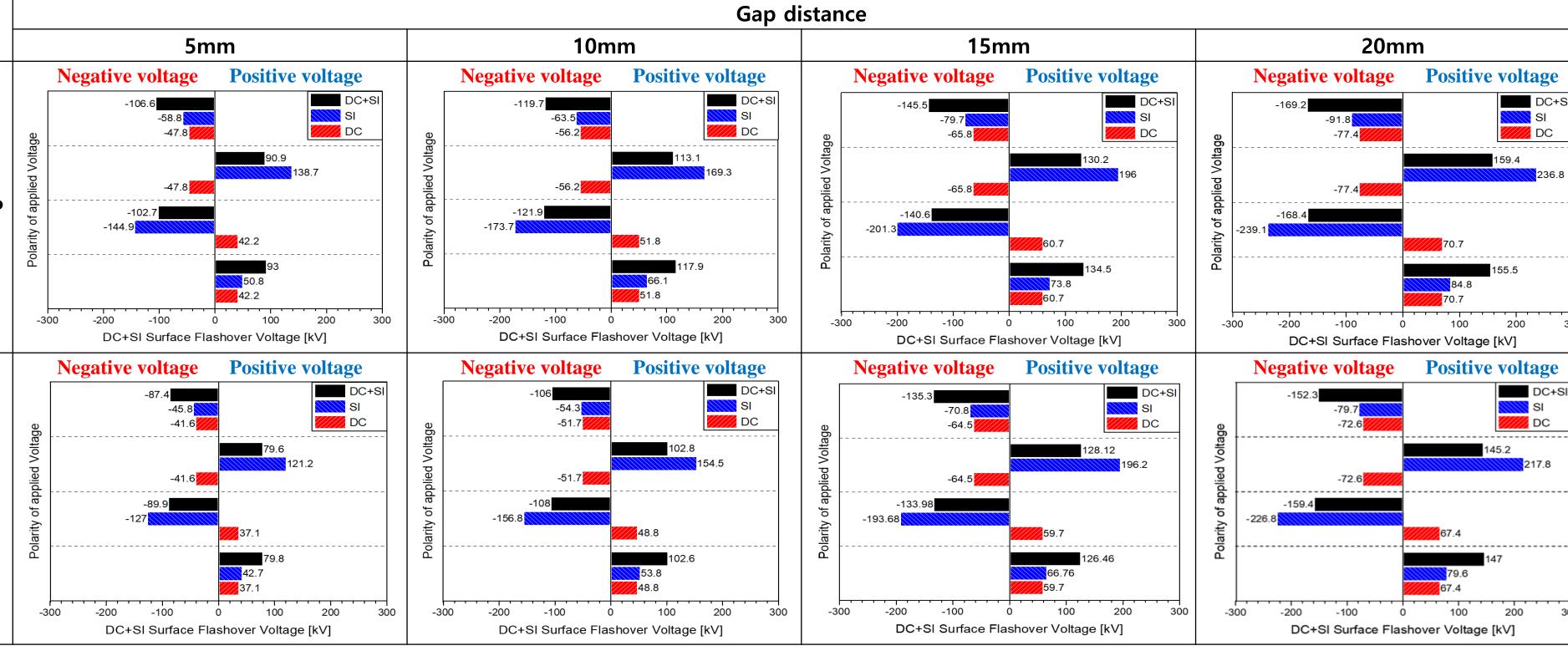


Fig. 6 surface breakdown voltage of GFRP and PTFE under DC+SI superimposed voltage

In order to evaluate the DC+SI surface dielectric breakdown characteristics of GFRP and PTFE, the polarity of the applied voltage and the gap distance were selected and the experiment was performed.

As the gap distance increased, both the SI and DC applied voltages rise regardless of the polarity and insulating material, so the superimposed SI+DC surface breakdown voltage increased.

the surface breakdown voltage of GFRP was measured to be higher than that of PTFE, but as the gap distance increased, the difference in surface breakdown voltage according to the insulating material decreased.

GFRP had a higher surface breakdown voltage when the polarities were the same, and PTFE had a high surface breakdown voltage when the polarities were different, but the difference according to polarity was insignificant.

• When only SI and DC applied voltages are considered, surface dielectric strength is the weakest when voltages of the same polarity are superimposed.



